Features
- Sub-harmonic, Image Reject Receiver
- Integrated LNA, Image Reject Mixer, LO Doubler/Buffer
- +2.0 dBm LO Drive Level
- 10.0 dB Conversion Gain
- 3.5 dB NF
- +5.0 dBm Input Third Order Intercept (IIP3)
- Lead-Free 7mm 28-lead SMD Package
- 100% RF and DC Testing
- RoHS* Compliant and 260°C Reflow Compatible

Description
The XR1008-QB is a 35.0-45.0 GHz packaged receiver that has a noise figure of 3.5 dB and 5.0 dBm Input Third Order Intercept across the band. This device integrates a three stage LNA followed by an image reject resistive pHEMT mixer and includes an integrated LO doubler and buffer amplifier. The use of integrated LO doubler and LO buffer amplifier makes the provision of the LO easier than for fundamental mixers at these frequencies. I and Q mixer outputs are provided and an external 90 degree hybrid is required to select the desired sideband.

The device comes in a 7x7mm SMT package that is RoHS compliant. This device has been designed for use in 38/42 GHz Point-to-Point Microwave Radio applications.

Pin Configuration

<table>
<thead>
<tr>
<th>Pin No.</th>
<th>Function</th>
<th>Pin No.</th>
<th>Function</th>
</tr>
</thead>
<tbody>
<tr>
<td>3</td>
<td>Ground</td>
<td>17</td>
<td>Ground</td>
</tr>
<tr>
<td>4</td>
<td>RF Input</td>
<td>18</td>
<td>LO Input</td>
</tr>
<tr>
<td>5</td>
<td>Ground</td>
<td>19</td>
<td>Ground</td>
</tr>
<tr>
<td>8</td>
<td>VG1</td>
<td>24</td>
<td>Ground</td>
</tr>
<tr>
<td>9</td>
<td>VG2</td>
<td>25</td>
<td>IF1 Output</td>
</tr>
<tr>
<td>10</td>
<td>Ground</td>
<td>26</td>
<td>Ground</td>
</tr>
<tr>
<td>11</td>
<td>IF2 Output</td>
<td>27</td>
<td>Drain Bias</td>
</tr>
<tr>
<td>12</td>
<td>Ground</td>
<td>All others</td>
<td>Not Connected</td>
</tr>
</tbody>
</table>

1. The exposed pad centered on the package bottom must be connected to RF and DC ground.

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit www.macom.com for additional data sheets and product information.
Electrical Specifications:

### Receiver

35 - 45 GHz

**Absolute Maximum Ratings**

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Absolute Max.</th>
</tr>
</thead>
<tbody>
<tr>
<td>Supply Voltage (Vd)</td>
<td>+4.3 VDC</td>
</tr>
<tr>
<td>Supply Current (Id)</td>
<td>300 mA</td>
</tr>
<tr>
<td>Gate Bias Voltage (Vg)</td>
<td>-1.5V &lt; Vg &lt; 0V</td>
</tr>
<tr>
<td>Input Power (Pin)</td>
<td>+5 dBm</td>
</tr>
<tr>
<td>Storage Temperature (Tstg)</td>
<td>-65 °C to +165 °C</td>
</tr>
<tr>
<td>Operating Temperature (Ta)</td>
<td>-55 °C to +85 °C</td>
</tr>
<tr>
<td>Channel Temperature (Tch)</td>
<td>175 °C</td>
</tr>
<tr>
<td>ESD - Human Body Model</td>
<td>Class 1A</td>
</tr>
<tr>
<td>ESD - Machine Body Model</td>
<td>Class A</td>
</tr>
<tr>
<td>Moisture Sensitivity Level</td>
<td>MSL3</td>
</tr>
</tbody>
</table>

**Recommended Layout**

---

2. Performance limits guaranteed over the frequency range 37.0-40.15 GHz

3. Channel temperature affects a device’s MTTF. It is recommended to keep channel temperature as low as possible for maximum life
Typical Performance Curves

XR1008-QB: USB Conversion Gain vs Frequency
Vd=4V, Id=180 mA, Pl=2 dBm, IF=2 GHz, 3.5 GHz

XR1008-QB: LSB Conversion Gain vs Frequency
Vd=4V, Id=180 mA, Pl=2 dBm, IF=2 GHz, 3.5 GHz

XR1008-QB: USB Image Rejection vs Frequency
Vd=4V, Id=180 mA, Pl=2 dBm, IF=2 GHz, 3.5 GHz

XR1008-QB: LSB Image Rejection vs Frequency
Vd=4V, Id=180 mA, Pl=2 dBm, IF=2 GHz, 3.5 GHz

XR1008-QB: USB Noise Figure vs Frequency
Vd=4V, Id=180 mA, Pl=2 dBm, IF=2 GHz, 3.5 GHz

XR1008-QB: LSB Noise Figure vs Frequency
Vd=4V, Id=180 mA, Pl=2 dBm, IF=2 GHz, 3.5 GHz

For further information and support please visit: https://www.macom.com/support
Typical Performance Curves (cont.)

MTTF

MTTF is calculated from accelerated life-time data of single devices and assumes an isothermal back-plate.

MTTF (yrs) vs. Backplate Temperature (°C)

Bias Conditions: Vd=4.0V, Id=180 mA
App Note [1] Biasing - Please refer to the functional block diagram and pin-out table for biasing information. The device is operated by biasing $V_D=4.0\ V$ with $I_D=180\ mA$ by adjusting the applied voltage on $V_G1$. $V_G1$ typically requires $-0.5\ V$ to result in the drain current being $180\ mA$. The nominal input impedance of this gate is $180\ \Omega$, so it should be noted that the nominal gate current will be $2.7\ mA$.

Additionally, a fixed bias of $V_G2=-0.5\ V$ is required to bias the mixer and doubler. Adjusting $V_G2$ above or below this value can adversely affect conversion gain, image rejection and intercept point performance. It is recommended to use active biasing to keep the currents constant as the RF power and temperature vary; this gives the most reproducible results. The diagram “Active Bias Circuit” demonstrates a possible method for active biasing. Depending on the supply voltage available and the power dissipation constraints, the bias circuit may be a single transistor or a low power operational amplifier, with a low value resistor in series with the drain supply used to sense the current. The gate of the pHEMT is controlled to maintain correct drain current and thus drain voltage. Typically the gate is protected with silicon diodes to limit the applied voltage. Also, make sure to sequence the applied voltage to ensure negative gate bias is available before applying the positive drain supply.

Active Bias Circuit
App Note [3] USB/LSB Selection - Please refer to the functional block diagram and pin-out table for biasing information. The device is operated by biasing VD=4.0 V with ID=180 mA by adjusting the applied voltage on VG1.

For Upper Side Band operation (USB):
With IF1 and IF2 connected to the direct port (0°) and coupled port (90°) respectively as shown in the diagram, the USB signal will reside on the isolated port. The input port must be loaded with 50 ohms.

For Lower Side Band operation (LSB):
With IF1 and IF2 connected to the direct port (0°) and coupled port (90°) respectively as shown in the diagram, the LSB signal will reside on the input port. The isolated port must be loaded with 50 ohms.

An alternate method of Selection of USB or LSB:
Typical Application

This 30.0-46.0 GHz XR1008-QB GaAs MMIC Receiver can be used in saturated radio applications and linear modulation schemes up to 128 QAM.
Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.
M/A-COM Technology Solutions Inc. All rights reserved. Information in this document is provided in connection with M/A-COM Technology Solutions Inc ("MACOM") products. These materials are provided by MACOM as a service to its customers and may be used for informational purposes only. Except as provided in MACOM's Terms and Conditions of Sale for such products or in any separate agreement related to this document, MACOM assumes no liability whatsoever. MACOM assumes no responsibility for errors or omissions in these materials. MACOM may make changes to specifications and product descriptions at any time, without notice. MACOM makes no commitment to update the information and shall have no responsibility whatsoever for conflicts or incompatibilities arising from future changes to its specifications and product descriptions. No license, express or implied, by estoppels or otherwise, to any intellectual property rights is granted by this document.

THESE MATERIALS ARE PROVIDED "AS IS" WITHOUT WARRANTY OF ANY KIND, EITHER EXPRESS OR IMPLIED, RELATING TO SALE AND/OR USE OF MACOM PRODUCTS INCLUDING LIABILITY OR WARRANTIES RELATING TO FITNESS FOR A PARTICULAR PURPOSE, CONSEQUENTIAL OR INCIDENTAL DAMAGES, MERCHANTABILITY, OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT. MACOM FURTHER DOES NOT WARRANT THE ACCURACY OR COMPLETENESS OF THE INFORMATION, TEXT, GRAPHICS OR OTHER ITEMS CONTAINED WITHIN THESE MATERIALS. MACOM SHALL NOT BE LIABLE FOR ANY SPECIAL, INDIRECT, INCIDENTAL, OR CONSEQUENTIAL DAMAGES, INCLUDING WITHOUT LIMITATION, LOST REVENUES OR LOST PROFITS, WHICH MAY RESULT FROM THE USE OF THESE MATERIALS.

MACOM products are not intended for use in medical, lifesaving or life sustaining applications. MACOM customers using or selling MACOM products for use in such applications do so at their own risk and agree to fully indemnify MACOM for any damages resulting from such improper use or sale.